Seminar "Topological Insulators"

The Su-Schrieffer-Heeger model

Seminar "Topological Insulators" Robin Kopp These slides are based on "A Short Course on Topological Insulators" by J. K. Asbóth, L. Oroszlány, A. Pályi; arXiv:1509.02295v1

Outline

- Introduction and the Su-Schrieffer-Heeger (SSH) model
- SSH Hamiltonian
- Bulk Hamiltonian
- Edge states
- Chiral symmetry
- Number of edge states as topological invariant

Introduction and the Su-Schrieffer-Heeger (SSH) model

- Simplest one-dimensional case
- Su-Schrieffer-Heeger model for polyacetylene



trans-polyacetylene, (https://en.wikipedia.org/wiki/Polya cetylene#/media/File:Trans-(CH)n.png)

- Insulator in the bulk but conduction at the surface via conducting edge states
- Nontrivial topology of occupied bands is crucial
- Dimensionality and basic symmetries of an insulator determine if it can be a topological insulator

SSH Hamiltonian

• Noninteracting model, single-particle lattice Hamiltonian, zero of energy corresponding to the Fermi energy, $\hbar=1$



Fig. 1.1 Geometry of the SSH model. Filled (empty) circles are sites on sublattice A(B), each hosting a single state. They are grouped into unit cells: the n = 6th cell is circled by a dotted line. Hopping amplitudes are staggered: intracell hopping v (thin lines) is different from intercell hopping w (thick lines). The left and right edge regions are indicated by blue and red shaded background.

 SSH-Model describes spinless fermions (electrons) hopping on a one-dimensional lattice with staggered hopping amplitudes

SSH Hamiltonian

• The dynamics of each electron is described by a single particle Hamiltonian

$$\hat{H} = v \sum_{m=1}^{N} \left(|m, B\rangle \langle m, A| + h.c. \right) + w \sum_{m=1}^{N-1} \left(|m+1, A\rangle \langle m, B| + h.c. \right)$$

- Study dynamics around ground state of SSH model at zero temperature and zero chemical poential
- For a chain consisting of N=4 unit cells the matrix of the Hamiltonian reads

$$=\begin{pmatrix} 0 & v & 0 & 0 & 0 & 0 & 0 & 0 \\ v & 0 & w & 0 & 0 & 0 & 0 & 0 \\ 0 & w & 0 & v & 0 & 0 & 0 & 0 \\ 0 & 0 & v & 0 & w & 0 & 0 & 0 \\ 0 & 0 & 0 & w & 0 & v & 0 & 0 \\ 0 & 0 & 0 & 0 & v & 0 & w & 0 \\ 0 & 0 & 0 & 0 & 0 & w & 0 & v \\ 0 & 0 & 0 & 0 & 0 & 0 & v & 0 \end{pmatrix}$$

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SSH Hamiltonian

 To emphasize the separation of external degrees of freedom (unit cell index m) and internal degrees of freedom (sublattice index) the following representation can be chosen:

Use tensor product basis: $|m, \alpha\rangle \rightarrow |m\rangle \otimes |\alpha\rangle \in \mathscr{H}_{external} \otimes \mathscr{H}_{internal}$ and the Pauli matrices: $\sigma_0 = \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}; \quad \sigma_x = \begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix}; \quad \sigma_y = \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix}; \quad \sigma_z = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix}$

This leads to the Hamiltonian

$$\hat{H} = v \sum_{m=1}^{N} |m\rangle \langle m| \otimes \hat{\sigma}_{x} + w \sum_{m=1}^{N-1} \left(|m+1\rangle \langle m| \otimes \frac{\hat{\sigma}_{x} + i\hat{\sigma}_{y}}{2} + h.c. \right)$$

Intracell hopping represented by intracell operator Intercell hopping represented by intercell operator

- Bulk: central part of the chain,
- Boudaries: the two ends or "edges" of the chain
- In the thermodynamic limit N→∞ the bulk determines the most important properties
- Bulk should not depend on definition of the edges, therefore for simplicity periodic boundary conditions (Born-von Karman)

$$\hat{H}_{\text{bulk}} = \sum_{m=1}^{N} \left(v \left| m, B \right\rangle \left\langle m, A \right| + w \left| (m \mod N) + 1, A \right\rangle \left\langle m, B \right| \right) + h.c.$$

with Eigenstates

$$\hat{H}_{\text{bulk}} |\Psi_n(k)\rangle = E_n(k) |\Psi_n(k)\rangle$$

Derivation of the bulk momentum-space Hamiltonian

 Start with plane wave basis states for external degree of freedom

$$|k\rangle = \frac{1}{\sqrt{N}} \sum_{m=1}^{N} e^{imk} |m\rangle$$
 for $k \in \{\delta_k, 2\delta_k, \dots, N\delta_k\}$ with $\delta_k = \frac{2\pi}{N}$

• Bloch eigenstates can be found:

 $|\Psi_n(k)\rangle = |k\rangle \otimes |u_n(k)\rangle$ $|u_n(k)\rangle = a_n(k) |A\rangle + b_n(k) |B\rangle$

where $|u_n(k)\rangle \in \mathscr{H}_{internal}$ are the eigenstates of the bulk momentum-space Hamiltonian

$$\hat{H}(k) = \langle k | \hat{H}_{\text{bulk}} | k \rangle = \sum_{\alpha, \beta \in \{A, B\}} \langle k, \alpha | H_{\text{bulk}} | k, \beta \rangle \cdot | \alpha \rangle \langle \beta |$$

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Periodicity in wavenumber:

 Fourier transform above acts only on the external degree of freedom →periodicity in the Brillouin zone

 $\hat{H}(k+2\pi) = \hat{H}(k)$ $|u_n(k+2\pi)\rangle = |u_n(k)\rangle$

 For a system consisting of N=4 unit cells with the bulk Hamiltonian and the Bloch eigenstates the matrix eigenvalue equation reads: (0 v 0 0 0 0 0 w) (a(k)e^{ik}) (a(k)e^{ik})

$$\begin{pmatrix} 0 & v & 0 & 0 & 0 & 0 & 0 & w \\ v & 0 & w & 0 & 0 & 0 & 0 & 0 \\ 0 & w & 0 & v & 0 & 0 & 0 & 0 \\ 0 & 0 & v & 0 & w & 0 & 0 & 0 \\ 0 & 0 & 0 & w & 0 & v & 0 & 0 \\ 0 & 0 & 0 & 0 & v & 0 & w & 0 \\ 0 & 0 & 0 & 0 & 0 & v & 0 & w & 0 \\ w & 0 & 0 & 0 & 0 & w & 0 & v \\ w & 0 & 0 & 0 & 0 & v & 0 & w \end{pmatrix} \begin{pmatrix} a(k)e^{ik} \\ b(k)e^{ik} \\ a(k)e^{2ik} \\ b(k)e^{2ik} \\ a(k)e^{3ik} \\ b(k)e^{3ik} \\ a(k)e^{Nik} \\ b(k)e^{Nik} \end{pmatrix} = E(k) \begin{pmatrix} a(k)e^{ik} \\ b(k)e^{ik} \\ a(k)e^{2ik} \\ a(k)e^{2ik} \\ a(k)e^{2ik} \\ a(k)e^{3ik} \\ a(k)e^{Nik} \\ b(k)e^{Nik} \end{pmatrix}$$

• For the bulk momentum-space Hamiltonian one can find:

$$H(k) = \begin{pmatrix} 0 & v + we^{-ik} \\ v + we^{ik} & 0 \end{pmatrix} \quad H(k) \begin{pmatrix} a(k) \\ b(k) \end{pmatrix} = E(k) \begin{pmatrix} a(k) \\ b(k) \end{pmatrix}$$

• With this equation one can find the dispersion relation

$$E(k) = |v + e^{-ik}w| = \sqrt{v^2 + w^2 + 2vw\cos k}$$



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- For staggered hopping amplitudes a gap of 2Δ seperates the lower filled band from the upper empty band
- If not staggered \rightarrow conductor $\Delta = \min_k E(k) = |v w|$
- Staggering is energetically favourable
- Internal structure of stationary states given by conponents of H(k): $d_x(k) = v + w \cos k;$ $d_y(k) = w \sin k;$ $d_z(k) = 0$
- Endpoint of vector for k=0→2π : closed loop, here circle, avoids origin for insulators. Topology of loop characterised by bulk winding number, number of times the loop winds around the origin of the xy-plane



Edge states

- Distinguish edge and bulk states by their localised/delocalised behaviour in the thermodynamic limit
- Fully dimerised limits: Intercell hopping vanishes, intracell hopping set to 1 or vice versa



- The bulk has flat bands here, A set of energy eigenstates restricted to one dimer each.
- Consist of even and odd superpositions of the two sites forming a dimer

Edge States

- "Trivial" Case: v=1, w=0: $\hat{H}(|m,A\rangle \pm |m,B\rangle) = \pm (|m,A\rangle \pm |m,B\rangle)$ $\rightarrow \hat{H}(k) = \hat{\sigma}_x$ independent of wavefunction k
- "Topological" Case: v=0, w=1: $\hat{H}(|m,B\rangle \pm |m+1,A\rangle) = \pm (|m,B\rangle \pm |m+1,A\rangle)$ $\rightarrow \hat{H}(k) = \hat{\sigma}_x \cos k + \hat{\sigma}_y \sin k$
- Energy eigenvalues independent of wavenumber k E(k) = 1
- Group velocity zero
- Edges can host zero energy states in this limit: In the topological case each end hosts an eigenstate at energy zero

$$\hat{H}|1,A\rangle = \hat{H}|N,B\rangle = 0$$

• Support on one side only, E=0 because no onsite pot. allowed

Edge States

Move away from fully dimerised limit by turning on v continuously



Chiral symmetry

- Definition: $\hat{\Gamma}\hat{H}\hat{\Gamma}^{\dagger} = -\hat{H}$ where $\hat{\Gamma}$ it unitary and Hermitian further requirements:
 - Local: for $m \neq m'$ is $\langle m, \alpha | \hat{\Gamma} | m', \alpha' \rangle = 0$ \rightarrow consists of $\hat{\Gamma} = \hat{\chi} \oplus \hat{\chi} \oplus \dots \oplus \hat{\chi} = \bigoplus_{n=1}^{N} \hat{\chi}$

$$1 \quad f \oplus f \oplus f \oplus f \oplus f \oplus f \oplus f = 1$$

- Robust: Independent of variation of local parameters
- Consequences:
 - Sublattice symmetry: By defining $\hat{P}_A = \frac{1}{2} \left(\mathbb{I} + \hat{\Gamma} \right)$, $\hat{P}_B = \frac{1}{2} \left(\mathbb{I} \hat{\Gamma} \right)$ and requiring no transitions from site to site on the same sublattice are induced by H: $\hat{P}_A \hat{H} \hat{P}_A = P_B \hat{H} \hat{P}_B = 0$ $\Rightarrow \hat{H} = \hat{P}_A \hat{H} \hat{P}_B + \hat{P}_B \hat{H} \hat{P}_A$

Chiral Symmetry

- Consequences:
 - Symmetric spectrum:

 $\hat{H} |\psi_n\rangle = E_n |\psi_n\rangle \implies \hat{H}\hat{\Gamma} |\psi_n\rangle = -\hat{\Gamma}\hat{H} |\psi_n\rangle = -\hat{\Gamma}E_n |\psi_n\rangle = -E_n\hat{\Gamma} |\psi_n\rangle$ - If $E_n \neq 0$ then $0 = \langle \psi_n | \hat{\Gamma} |\psi_n\rangle = \langle \psi_n | P_A |\psi_n\rangle - \langle \psi_n | P_B |\psi_n\rangle$

If $E_n = 0$ zero energy eigenstates can be chosen to have support only on one sublattice.

Chiral Symmetry

- Bulk winding number
 - Recall vector **d**(k), restricted to xy-plane due to chiral symmetry $\sigma_z \hat{H}(k) \sigma_z = 0 \rightarrow d_z = 0$
 - Endpoint curve direct closed loop on plane, well defined integer winding number, has to avoid origin (insulator)
 - Integral definition of winding number:

$$\begin{split} \tilde{\mathbf{d}} &= \frac{\mathbf{d}}{|\mathbf{d}|} \qquad \mathbf{v} = \frac{1}{2\pi} \int \left(\tilde{\mathbf{d}}(k) \times \frac{d}{dk} \tilde{\mathbf{d}}(k) \right)_z dk \qquad H(k) = \begin{pmatrix} 0 & h(k) \\ h^*(k) & 0 \end{pmatrix} \\ h(k) &= d_x(k) - i d_y(k) \qquad \qquad \mathbf{v} = \frac{1}{2\pi i} \int_{-\pi}^{\pi} dk \frac{d}{dk} \log h(k) \end{split}$$

Winding Number of SSH model

- Trivial case with dominant intracell hopping winding number 0
- Topological case: winding number 1
- To change the winding number of the SSH model eiter close



bulk gap or break chiral symmetry.

- Definition of adiabatic deformation of insulating Hamiltonian
 - Continous change of parameters
 - Maintaining important symmetries
 - Keeping the gap around zero energy open
- Definition of adiabatic equivalence of Hamiltonians
 - Two insulating Hamiltonians are adiabatically connected if they are connected by adiabatic transformation
 - Path can be drawn that does not cross gapless phase boundary w=v



- Topological invariant
 - Integer number characterising insulating Hamiltonian if it cannot change under adiabatic deformations
 - Only well defined in thermodynamic limit,
 - Depends on Symmetries that need to be respected
 - Winding Number of SSH model is topological invariant
- Number of edge states as topological invariant
 - Gapped chiral symmetric one-dimensional Hamiltonian
 - Energy window $-\varepsilon < E < \varepsilon$ where ε is the bulk gap
 - Zero and nonzero edge states possible
 - Nonzero energy state has chiral symmetric parnter occupying same unit cell

- Finite number of zero energy states (bulk gap)
- Restriction to single sublattice: N_A states on sublattice A and N_B states on sublattice B
- Consider effect of adiabatic deformation with continuous parameter d: $0 \rightarrow 1$ on $N_A N_B$
 - Nonzero energy edge state can be brought to zero energy for $d \ge d'$
 - Chiral symmetric partner moves simultaneously to zero energy

 $|\Psi_0(d=0)\rangle$ $\Gamma |\Psi_0(d)\rangle$ $E_0(d)=0$

 $\hat{P}_A |\Psi_0(d')\rangle \qquad \hat{P}_B |\Psi_0(d')\rangle$

– $N_A - N_B$ unchanged

- Timereverse process also possible, bring zero energy state to nonzero energy at time d=d'
 - Both sublattice numbers decrease by one so difference unchanged
- Bringing nonzero energy states out of the energy range of above does not change difference
- Zero energy eigenstate can change, extending deeper into the bulk; due to gap condition exponential decay of wavefunction
 - Cannot move states away from the edge, thus no change of the numbers
- $N_A N_B$ is net number of edge states on sublattice A at the left edge
 - This is a topological invariant.
- Winding number (bulk) allows predictions about low energy physics at the edge: trivial case both zero, topological case both one
 - Example for bulk-boundary correspondence

• Consider interfaces between different insulating domains



- $\hat{H}(|6,B\rangle |7,B\rangle) = 0$ zero energy eigenstate
- Consider SSH system that is not in the fully dimerized limit
 - Edge state wave functions at domain walls penetrate into the bulk
 - Hybridization of two edge states at domainwalls with distance M forming bonding and anti-bonding states
 - Only negative energy eigenstate will be occupied at half filling
 - Each domain wall carries half an electronic charge: fractionalisation

• Zero energy edge states can be calculated without translational invariance

$$\hat{H} = \sum_{m=1}^{N} \left(v_m | m, B \rangle \langle m, A | + h.c. \right) + \sum_{m=1}^{N-1} \left(w_m | m+1, A \rangle \langle m, B | + h.c. \right)$$
$$\hat{H} \sum_{m=1}^{N} \left(a_m | m, A \rangle + b_m | m, B \rangle \right) = 0$$

$$m = 1, \dots, N - 1: \qquad v_m a_m + w_m a_{m+1} = 0; \qquad w_m b_m + v_{m+1} b_{m+1} = 0$$

boundaries:
$$v_N a_N = 0; \qquad v_1 b_1 = 0$$

$$m = 2, \dots, N: \qquad a_m = \prod_{j=1}^{m-1} \frac{-v_j}{w_j} a_1;$$

$$m = 1, \dots, N-1: \qquad b_m = \frac{-v_N}{w_m} \prod_{j=m+1}^{N-1} \frac{-v_j}{w_j} b_N$$

• In general no zero energy state but approximately in the thermodynamic limit for strong intercell hopping

 $\overline{\log |v|} = \frac{1}{N-1} \sum_{m=1}^{N-1} \log |v_m|; \qquad \overline{\log |w|} = \frac{1}{N-1} \sum_{m=1}^{N-1} \log |w_m|$ $|a_N| = |a_1| e^{-(N-1)/\xi}; \qquad |b_1| = |b_N| e^{-(N-1)/\xi} \frac{|v_N|}{|v_1|}$ $- \text{ Localisation length } \xi = \frac{1}{\overline{\log |w|} - \overline{\log |v|}}$ $- \text{ for } \xi > 0 \quad \text{solutions}$

$$|L\rangle = \sum_{m=1}^{N} a_m |m, A\rangle; \qquad |R\rangle = \sum_{m=1}^{N} b_m |m, B\rangle$$

- Exponentially small hybridisation of states above under H
- Overlap central quantity $\langle R|\hat{H}|L\rangle = \left|a_1e^{-(N-1)/\xi}v_Nb_N\right|e^{i\phi}$
- This leads to approximated energy eigenstates and energies

$$|0+\rangle = \frac{e^{-i\phi/2} |L\rangle + e^{i\phi/2} |R\rangle}{\sqrt{2}}; \qquad E_{+} = \left| a_{1} e^{-(N-1)/\xi} v_{N} b_{N} \right|;$$
$$|0-\rangle = \frac{e^{-i\phi/2} |L\rangle - e^{i\phi/2} |R\rangle}{\sqrt{2}}; \qquad E_{-} = -\left| a_{1} e^{-(N-1)/\xi} v_{N} b_{N} \right|$$

• Energy exponentially small in the system size (N)

This is the end!

Thank you for your attention!